



dRICH photosensors and electronics

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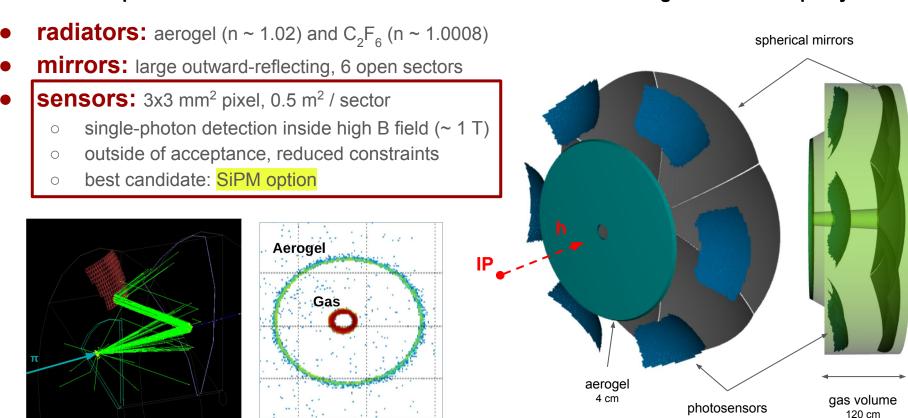
on behalf of the dRICH Collaboration

preghenella@bo.infn.it PID review, 6 July 2023

The dual-radiator (dRICH) for forward PID at EIC



compact and cost-effective solution for broad momentum coverage at forward rapidity



SiPM option and requirements for RICH optical readout







- cheap
- high photon efficiency
 requirement
- excellent time resolution
- insensitive to magnetic field
 requirement



cons

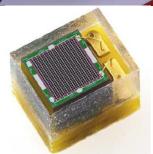
large dark count rates not radiation tolerant

technical solutions and mitigation strategies

cooling timing

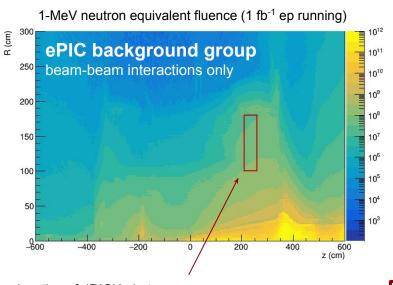
annealing





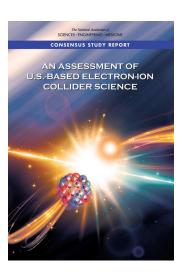
Neutron fluxes at the dRICH photosensor surface





Most of the key Physics goals defined by the NAS require an integrated luminosity of 10 fb⁻¹ per center of mass energy and polarization setting

The nucleon imaging programme is more luminosity hungry and requires 100 fb⁻¹ per center of mass energy and polarization setting



in 10-12 years the EIC will accumulate 1000 fb⁻¹ integrated \pounds corresponding to an integrated fluence of ~ 10^{10} n_{eq}/cm²

location of dRICH photosensors

mean fluence: $3.9 ext{ } 10^5 ext{ neq / cm}^2 ext{ / fb}^{-1}$ max fluence: $9.2 ext{ } 10^5 ext{ neq / cm}^2 ext{ / fb}^{-1}$

radiation level is moderate

assume fluence: ~ 10⁷neq / cm² / fb⁻¹ conservatively assume max fluence and 10x safety factor

study the SiPM usability for single-photon Cherenkov imaging applications in moderate radiation environment

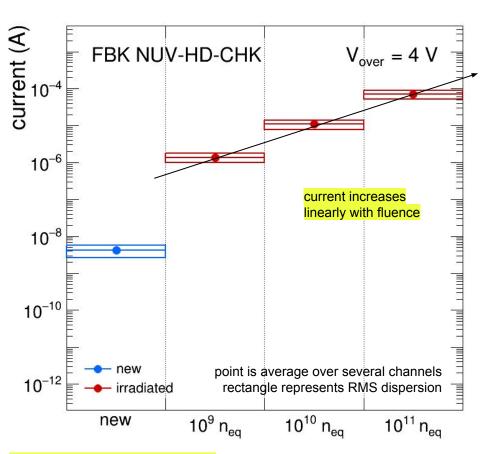
→ radiation damage studied in steps of radiation load

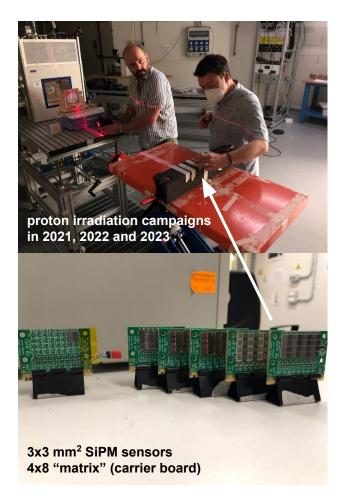
 10^9 1-MeV $n_{\rm eq}/{\rm cm}^2$ 10^{10} 1-MeV $n_{\rm eq}/{\rm cm}^2$ 10^{11} 1-MeV $n_{\rm eq}/{\rm cm}^2$

most of the key physics topics should cover most demanding measurements might never be reached

Studies of radiation damage on SiPM

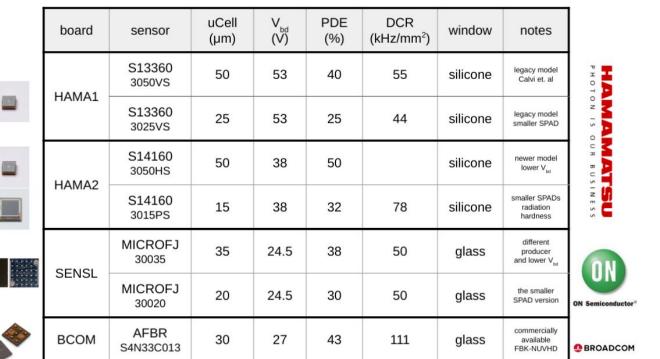


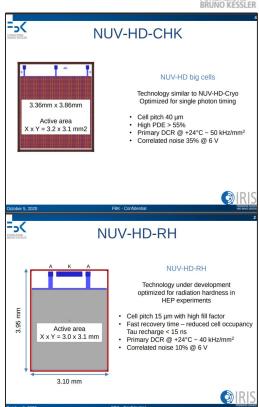




Commercial SiPM sensors and FBK prototypes



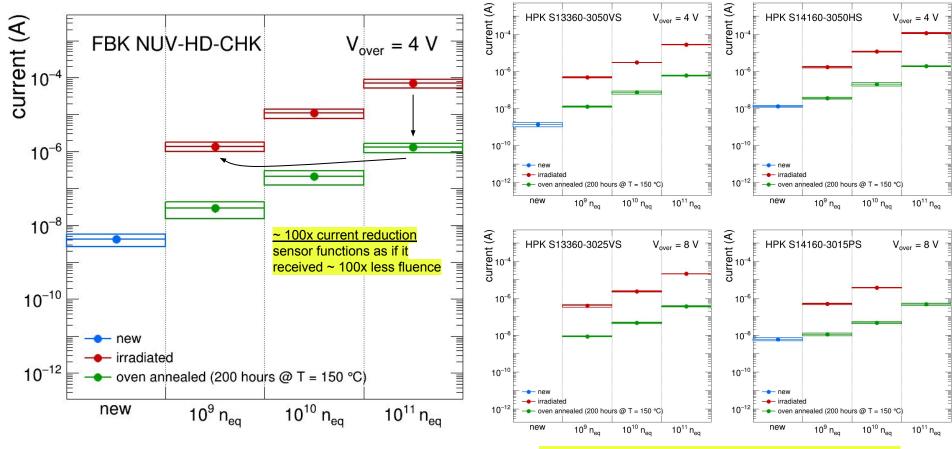




High-temperature annealing recovery

oven annealing ~ 1 week at 150 C

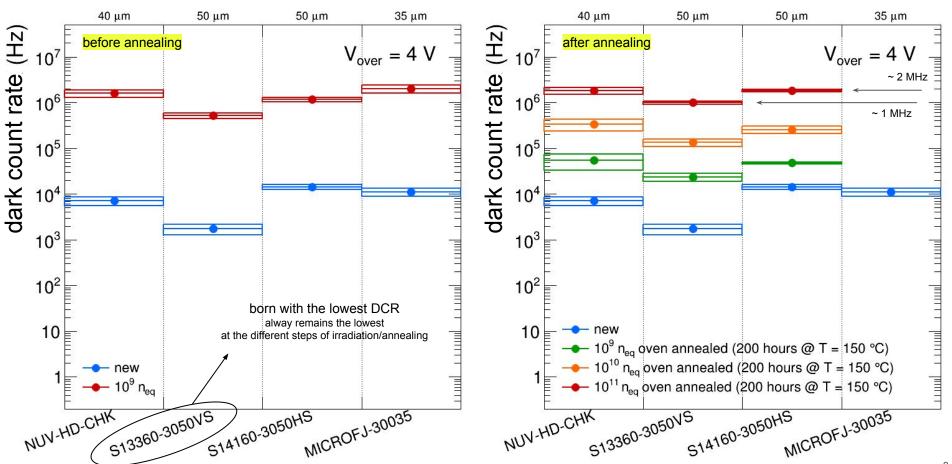




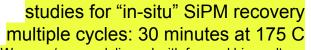
Comparison between different sensors

comparison at same Vover not totally fair

important to consider PDE (and SPTR) → SNR ~ PDE / DCR unlikely 2x larger DCR is matched by 2x larger PDE

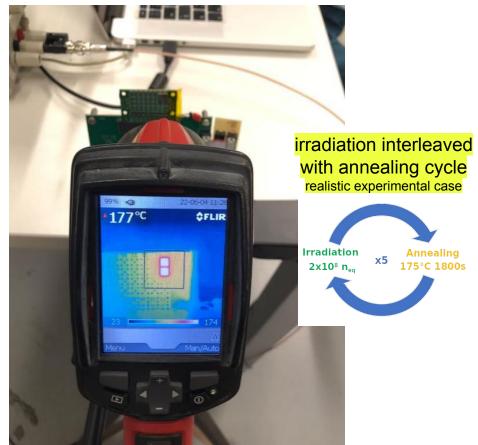


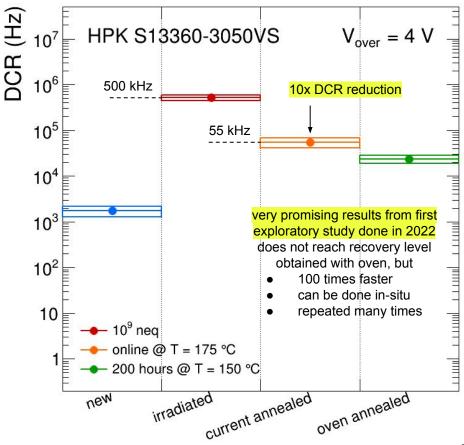
"Online" self-induced annealing

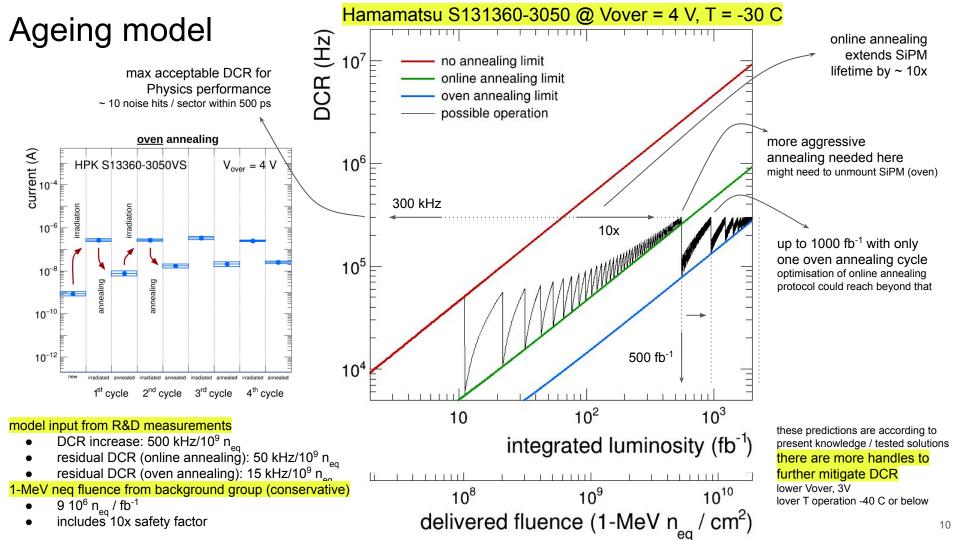




~ 1 W power/sensor delivered with forward bias voltage



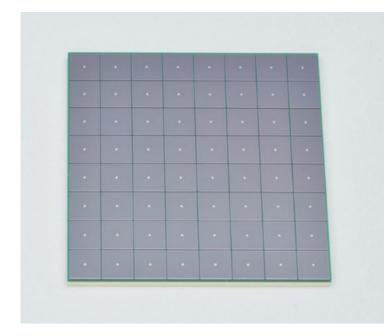




SiPM technical specs

baseline sensor device

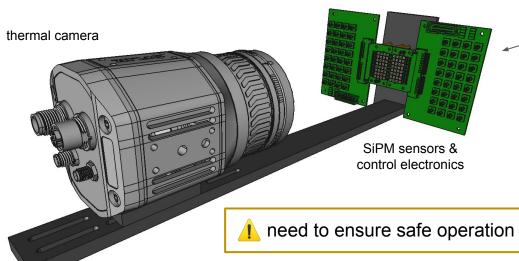
64 (8x8) channel SiPM array 3x3 mm² / channel



Parameters (at Vop, T = 25 C, unless specified)	Symbol	Value	Notes
Package type		SiPM array	
Mounting technology		surface mount	wire bonding also acceptable
Number of channels		64 (8 x 8)	8 (2 x 4) also acceptable
Effective photosensitive area / channel		3 x 3 mm ²	
Package dimension		< 26 x 26 mm ²	
Fraction of active area in package		> 85 %	
Microcell pitch		50 or 75 um	
Number of microcells	Nspad	> 1500	
Protective window material		Silicone resin	radiation / heat resistant
Protective window refractive index		1.55 - 1.57	
Spectral response range		300 to 900 nm	
Peak sensitivity wavelength	Lambda	400 - 450 nm	
Photon detection efficiency at Lambda		> 40%	
Breakdown voltage	Vbreak	< 60 V	
Operating overvoltage	Vover	< 5 V	
Operating voltage	Vop	Vbd + Vover	
Max Vop variation between channels		< 100 mV	at T = -30 C
Dark count rate	DCR	< 500 kHz	
DCR at T = -30 C		< 5 kHz	at T = -30 C
DCR increase with radiation damage		< 500 kHz / 109 neq	at T = -30 C
Residual DCR after annealing		< 50 kHz / 109 neq	at T = -30 C
Terminal capacitance		< 500 pF	
Gain		> 1.5 106	
Recharge time constant	Tau	< 100 ns	
Crosstalk	CT	< 5%	
Afterpulsing	AP	< 5%	
Operating temperature range		-40 C to 25 C	
Single photon time resolution	SPTR	< 200 ps FWHM	1

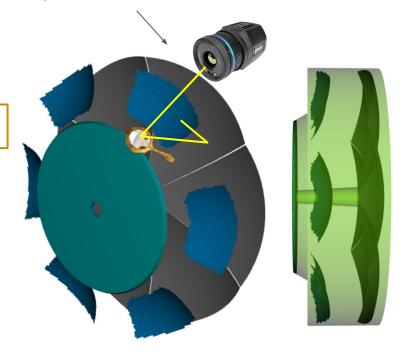
Automated multiple SiPM online self-annealing



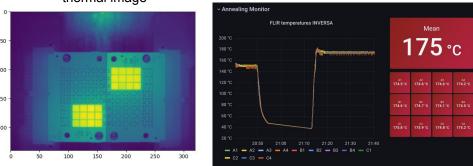


demonstrator system for online temperature monitor and control of each individual SiPM

technical feasibility and implementation in the experimental environment to be studied in details



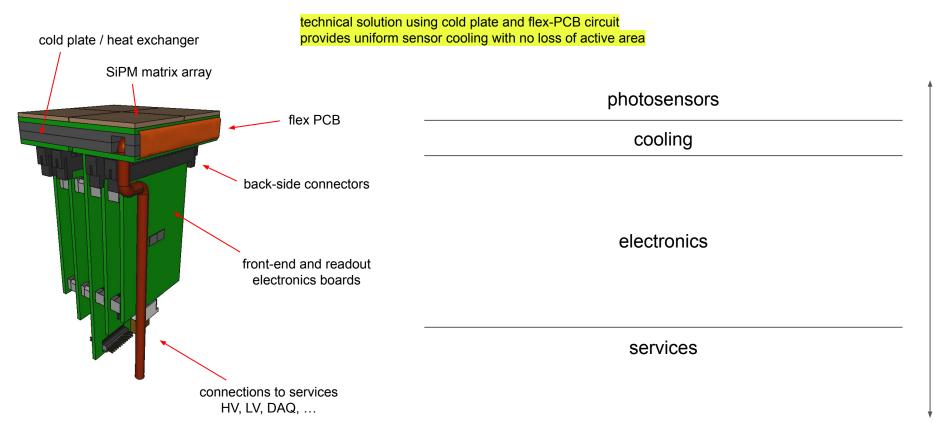
thermal image monitor system

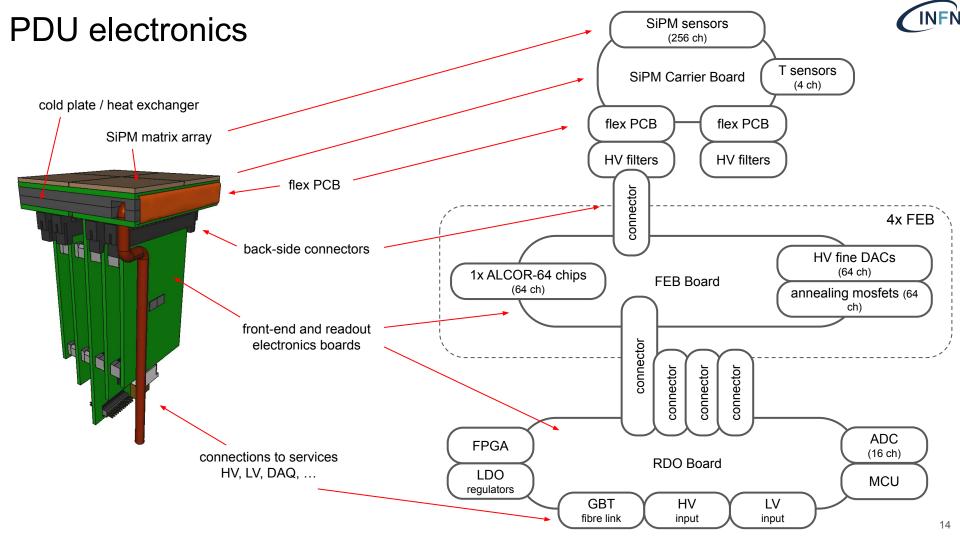


15-20 cm

SiPM photodetector unit – PDU

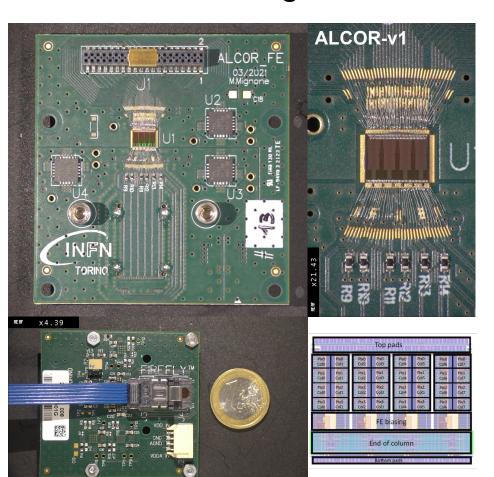






ALCOR ASIC: integrated front-end and TDC





developed by INFN-TO

64-pixel matrix mixed-signal ASIC current versions (v1,v2) have 32 channels, wirebonded final version will have 64 channels, BGA package, 394.08 MHz clock

the chip performs

- signal <u>amplification</u>
- conditioning and event <u>digitisation</u>

each pixel features

- 2 leading-edge discriminators
- 4 TDCs based on analogue interpolation
 - 20 or 40 ps LSB (@ 394 MHz)
- digital shutter to enable TDC digitisation
 - <u>suppress out-of-gate DCR</u> hits
 - 1-2 ns timing window
 - programmable delay, sub ns accuracy

single-photon time-tagging mode

- o continuous readout
- also with Time-Over-Threshold

fully digital output

8 LVDS TX data links

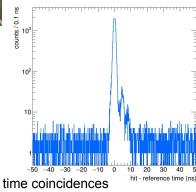
2022 test beam at CERN-PS

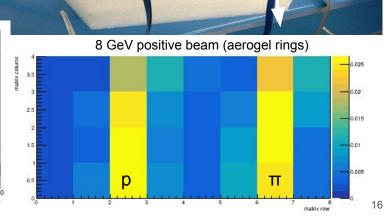




successful operation of SiPM

<u>irradiated</u> (with protons up to 10¹⁰) and <u>annealed</u> (in oven at 150 C)

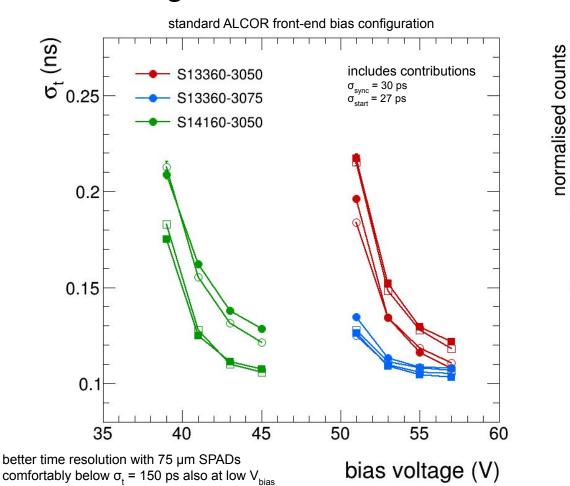


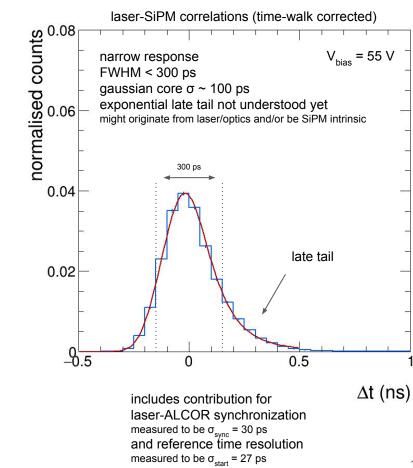


ALCOR

inside

Laser timing measurements with ALCOR





Current & future plans: sensor optimisation and risk mitigation

characterisation measurements

- measurements of <u>time resolution</u> after irradiation and annealing
- o define SiPM performance and comparisons based on <u>SNR</u> (DCR, PDE, SPTR)
- o full evaluation of <u>75 µm SPAD</u> sensors (ie. Hamamatsu S13360-3075)
 - PDE is larger than 50 μm, SPTR is better, DCR is similar
- o full evaluation of <u>new Hamamatsu SiPM</u> prototypes (based on S13360 technology)
 - improved NUV sensitivity, improved signal shape and recharge time
 - already received 50 μm and 75 μm samples

operation and annealing

- o test low-temperature (down to T = -40 C) operation with <u>fluid-based chiller</u>
 - evaluate possibility of using the system in heating mode for annealing
- o study the details of "in-situ" online self-induced annealing
 - forward (safer, but larger currents) vs. reverse (less safe, lower currents) bias operation
 - recovery vs. annealing temperature and time
 - refine technical solutions (and electronics) for monitor and control in the experiment

engineering run with FBK

- optimisations for the EIC of the already-mature NUV-HD technology (lower field / shaping to improve DCR)
- o development of single-die multi-channel SiPM sensor (achieve high fraction of active area with a low-cost process)

This list is not exhaustive and only contains the most important items and steps towards the TDR



Summary



dRICH SiPM option fulfills dRICH requirements

- magnetic field limitations
- excellent timing and efficiency

technical solutions to mitigate radiation damage

- low temperature operation
- online "in-situ" self-annealing
- extend lifetime of good detector performance for Physics
 - present solutions can be optimised/improved to extend it further

SiPM readout with full electronics chain

- based on ALCOR ASIC
- successful beam test at CERN-PS in 2022
- overall 1-pe time resolution approaching 100 ps

clear path for optimisation towards TDR

- good feeling on 75 μm SPAD sensors
- new Hamamatsu prototypes and FBK developments
- development of RDO
- ALCOR-v3, optimisation and final packaging